



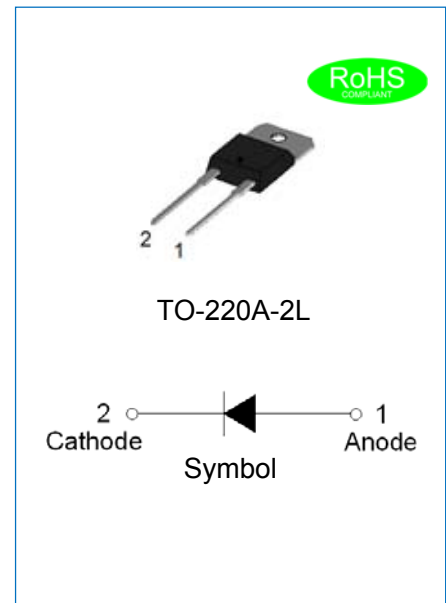
JECR0806AL-D

TANDEM EPI HYPERFAST RECOVERY RECTIFIER

Rev.1.1

DESCRIPTION

- ✧ Plastic package has underwriters laboratory flammability classification 94V-0
- ✧ Lead free in comply with EU RoHS 2011/65/EU directives
- ✧ Low reverse leakage current
- ✧ Hyperfast recovery time and soft recovery characteristics
- ✧ Low recovery loss
- ✧ Internal ceramic insulated devices with equal thermal conditions for both 300V diodes
- ✧ Applications for continuous current mode (CCM) power factor correction (PFC)
- ✧ Insulation (2500V_{RMS}) allows placement on same heatsink as mosfet and flexible heatsinking on common or separate heatsink



MECHANICAL DATA

- ✧ Case: TO-220A-2L molded plastic over passivated junction
- ✧ Terminals: Solder plated, solderable per J-STD-002
- ✧ Internally constructed isolated package is offered for ease of heat sinking with highest isolation voltage
- ✧ Weight:2.1gram

ABSOLUTE MAXIMUM RATING (Rating at 25°C case temperature unless otherwise specified.)

Parameter	Symbol	JECR0806AL-D	Unit
Maximum repetitive peak reverse voltage	V _{RRM}	600	V
Maximum RMS voltage	V _{RMS}	420	V
Maximum DC blocking voltage	V _{DC}	600	V
Maximum average forward current at T _C =100°C	I _{F(AV)}	8	A
Peak forward surge current: 10ms single half sine-wave superimposed on rated load	I _{FSM}	150	A
Junction temperature and storage temperature range	T _j , T _{stg}	-55 to +175	°C

ISOLATION CHARACTERISTICS

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
$V_{isol(RMS)}$	RMS isolation voltage	50Hz≤f≤60Hz;RH≤65%;from all pins to external heatsink; sinusoidal waveform; clean and dust free	-	-	2500	V
C_{isol}	Isolation capacitance	from cathode to external heatsink	-	10	-	pF

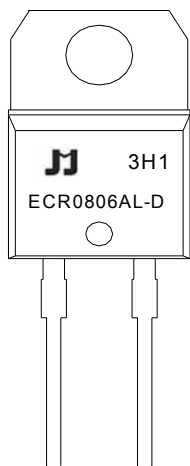
ELECTRICAL CHARACTERISTICS(Rating at 25°C case temperature unless otherwise specified.)

Parameter		Symbol	Min.	Typ.	Max.	Unit
Forward voltage	$I_F=8A, T_J=25^\circ C$	V_F	-	-	3.6	V
	$I_F=8A, T_J=150^\circ C$		-	1.95	2.4	
Reverse current at rated DC blocking voltage	$T_J=25^\circ C$	I_R	-	-	5	μA
	$T_J=150^\circ C$		-	-	200	
Reverse recovery time	$I_F=0.5A, I_{rr}=0.25A, I_R=1A, T_J=25^\circ C$	t_{rr}	-	13	-	ns
	$I_F=1A, V_R=30V, di/dt=-50A/\mu s, T_J=25^\circ C$		-	-	30	
Peak reverse recovery current	$I_F=8A, V_R=400V, di/dt=-200A/\mu s, T_J=125^\circ C$	I_{RM}	-	4	5.5	A
Recovered charge	$I_F=8A, V_R=400V, di/dt=-200A/\mu s, T_J=125^\circ C$	Q_r	-	50	-	nC
Reverse recovery softness factor	$I_F=8A, V_R=400V, di/dt=-200A/\mu s, T_J=125^\circ C$	S	-	0.4	-	-

THERMAL RESISTANCES

Symbol	Parameter	Min.	Typ.	Max.	Unit
$R_{th(j-c)}$	Thermal resistance from junction to case	-	2.6	-	°C/W

MARKING



ECR	EPI Hyperfast Recovery Rectifier
08	$I_{F(AV)}=8A$
06	$V_{RRM}:600V$
AL	Package:TO-220A-2L
D	Double chip

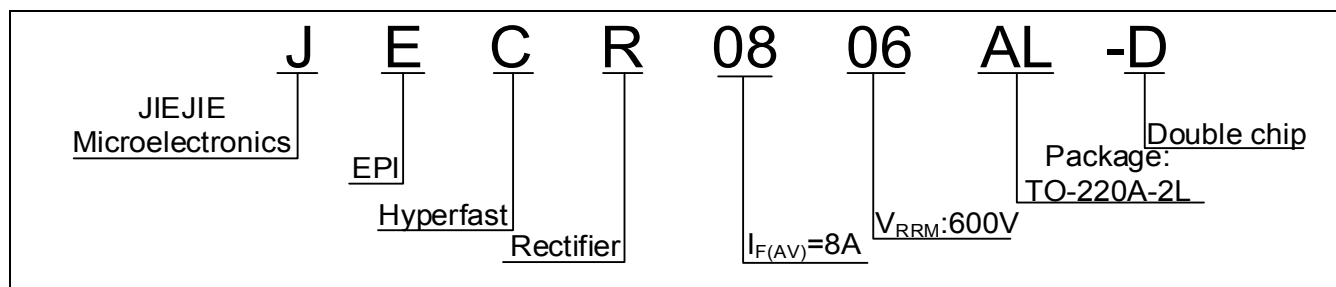
$\underline{x}H1$: Month, 1, 2, 3 ~ 9, A, B, C

$3\underline{x}1$:

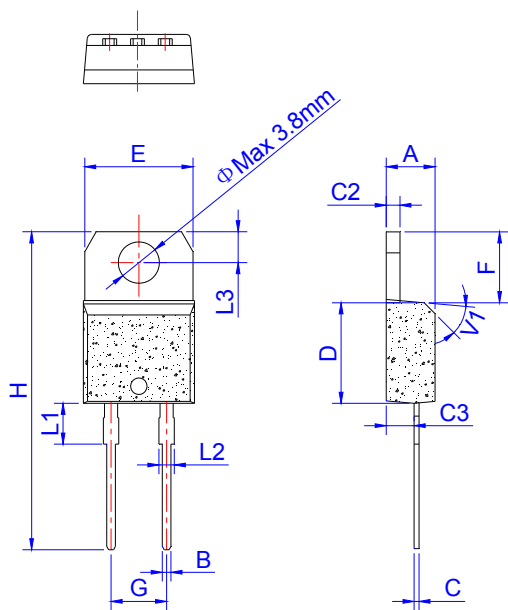
2018	2019	2020	2021	2022	2023	2024
H	I	J	K	L	M	N
2025	2026	2027	2028	2029	2030	...
O	P	Q	R	S	T	...

$3H\underline{x}$: Batch number

ORDERING INFORMATION



PACKAGE MECHANICAL DATA



TO-220A-2L Ins

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	0.61		0.88	0.024		0.035
C	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
E	9.80		10.4	0.386		0.409
F	6.55		6.95	0.258		0.274
G		5.08			0.1	
H	28.0		29.8	1.102		1.173
L1		3.75			0.148	
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	

PACKAGE INFORMATION-TO-220A-2L

OUTLINE	UNIT WEIGHT (g/PCS) typ.	TUBE (PCS)	PER CARTON (PCS)
TUBE	2.1	50	5,000

CHARACTERISTICS CURVE

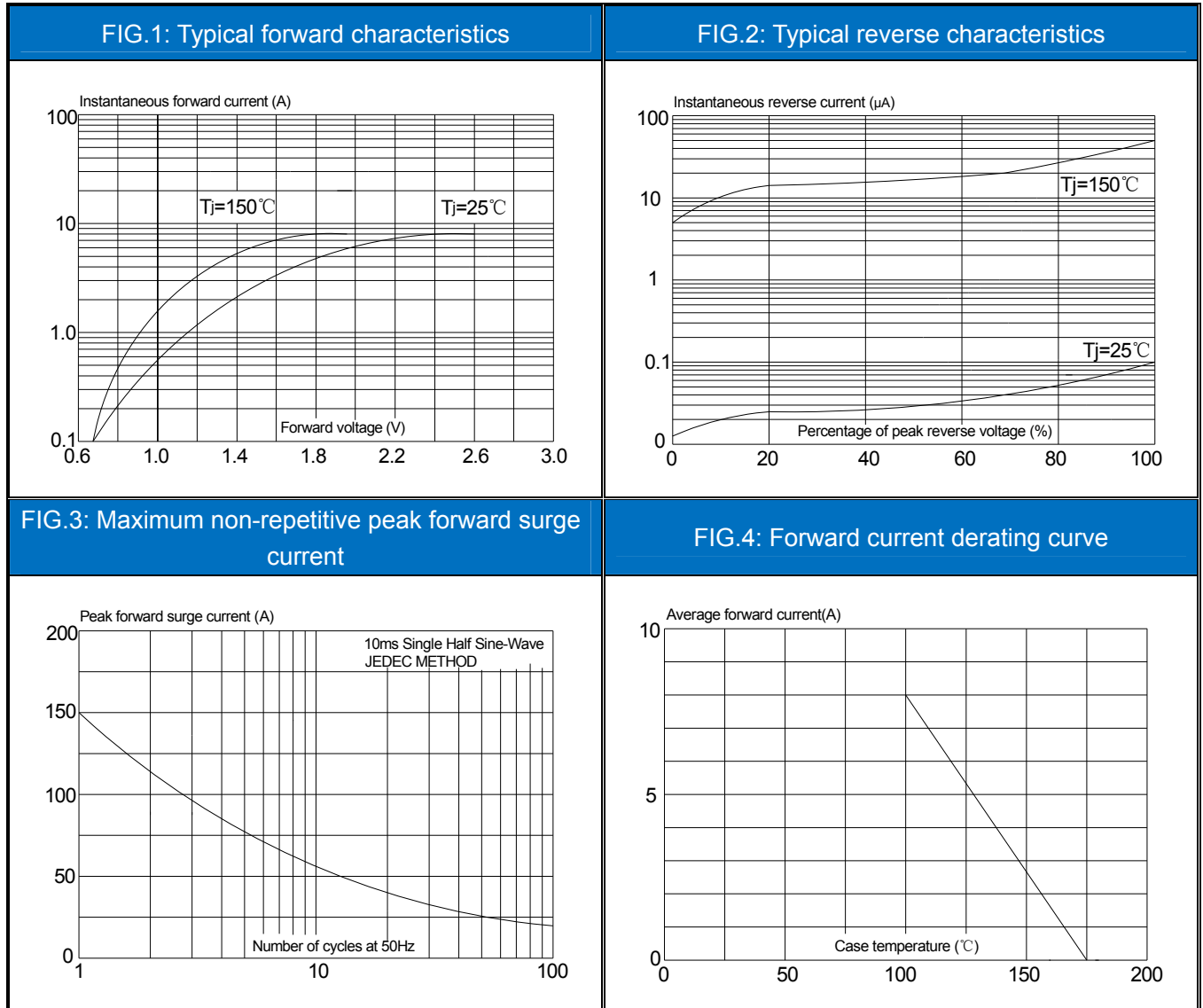


FIG.5: Forward power dissipation vs. average forward current (square waveform)

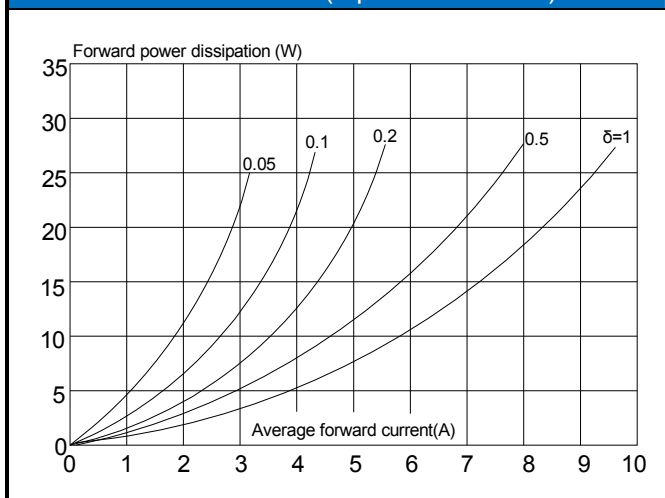
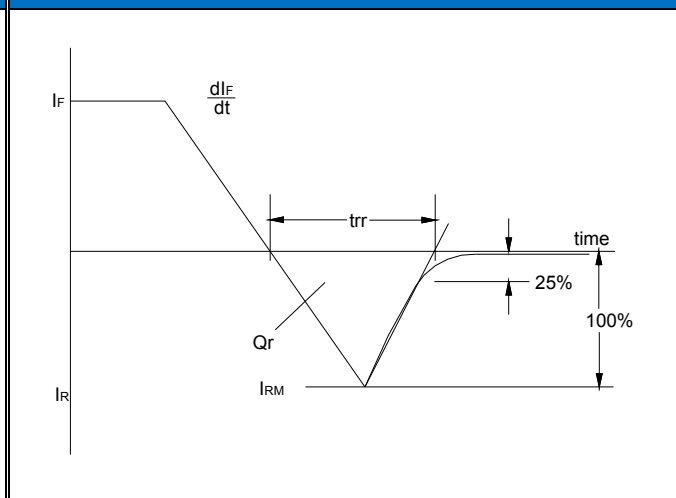


FIG.6: Reverse recovery definitions




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